Substitute for Form 14	49 A & R/PTO		Complete if Known		
Constitute for Form 14	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,		Application Number	Unknown	
INFO	RMATION	DISCLOSURE	Confirmation Number	Unknown	
STAT	EMENT B	Y APPLICANT	Filing Date	September 18, 2003	
			First Named Inventor	Katsumi ABE	
(us	e as many shee	ts as necessary)	Art Unit	Unknown	
			Examiner Name	Unknown	
Sheet	1	of 1	Attorney Docket Number	Q75817	

			U.S.	PATENT DOCUM	ENTS
Examiner Initials*		Document N	lamber		
		Number	Kind Code <sup>2</sup> ((f known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document
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Examiner Initials*	Cite No.1	Foreign Patent Document			Publication Date	Name of Patentee or	
		Country Code <sup>3</sup>	Number <sup>4</sup>	Kind Code <sup>5</sup> (if known)	MM-DD-YYYY	Applicant of Cited Document	Translation
TP/		JР	11-194320	A	07/21/1999		
TP/		JP	11-194316	Α	07/21/1999		
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Examiner Initials*	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city, and/or country where published.	Translation
/TP/		T. Nakamura et al., "Low-Temperature Poly-Si TFT-LCD with Integrated Analog Circuit", Asia Display/IDW 01 Proceedings, October 16, 2001, pp. 1603-1606 with Abstract.	
TP/		Y. Mikami et al., "A 5-in. SVGA TFT-LCD with Integrated Multiple DAC Using Low-Temperature poly-Si TFTs", Asia Display/IDW 01 Proceedings, October 16, 2001, pp. 1607-1610 with Abstract.	
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Examiner Signature /Tammy Pham/ (04/17/2007)  Date Considered	Date Considered

<sup>\*</sup>EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

<sup>&</sup>lt;sup>1</sup>Applicant's unique citation designation number (optional). <sup>2</sup>See Kind Codes of USPTO Patent Documents at www.uspto.gov, MPEP 901.04 or in the comment box of this document. <sup>3</sup> Enter Office that issued the document, by the two-letter code (WIPO Standard ST. 3). <sup>4</sup>Por Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. <sup>5</sup>Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. <sup>6</sup> Applicant is to indicate here if English

Substitute for Form 144	10 A & B/PTO			Complete if Known			
Substitute for Form 1449 A & B/FTO				Application Number	Unknown		
INFO	RMATION:	DISCLOS	URE	Confirmation Number	Unknown		
STAT	EMENT BY	APPLIC	ANT	Filing Date	September 18, 2003		
				First Named Inventor	Katsumi ABE		
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				Examiner Name	Unknown		
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Initials*	No. 1 Country Code 1 Number 4 Kind Code 3 MM-DD-YYYY (if known)		Applicant of Cited Document	Translation <sup>6</sup>			
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7117		Display/IDW 01 Proceedings, October 16, 2001, pp. 1603-1606 with Abstract.	
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7117		Si TFTs", Asia Display/IDW 01 Proceedings, October 16, 2001, pp. 1607-1610 with Abstract.	

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¹Applicant's unique citation designation number (optional). ¹See Kind Codes of USPTO Patent Documents at www.uspto.gov, MPEP 901.04 or in the comment box of this document. ¹ Enter Office that issued the document, by the two-letter code (WIPO Standard ST. 3). ⁴For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ¹Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁴ Applicant is to indicate here if English language Translation is attached.

Substitute for Form 1449 A & B/PTO	Comp	Complete if Known		
	Application Number	Unknown		
INFORMATION DISCLOSURE	Confirmation Number	Unknown		
STATEMENT BY APPLICANT	Filing Date	September 18, 2003		
,	First Named Inventor	Katsumi ABE		
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	Examiner Name	Unknown		
Sheet 1 of 1	Attorney Docket Number	Q75817		

			U.S.	PATENT DOCUM	ENTS
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Examiner Initials*	Cite No.1	Foreign Patent Document			Publication Date	Name of Patentee or	
		Country Code <sup>3</sup>	Number <sup>4</sup>	Kind Code <sup>5</sup> (if known)	MM-DD-YYYY	Applicant of Cited Document	Translation <sup>6</sup>
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7177		Display/IDW 01 Proceedings, October 16, 2001, pp. 1603-1606 with Abstract.	
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7117		Si TFTs", Asia Display/IDW 01 Proceedings, October 16, 2001, pp. 1607-1610 with Abstract.	
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